

TOSHIBA Photocoupler GaAs Ired & Photo-Transistor

# TLP624, TLP624-2, TLP624-4

Programmable Controllers  
AC/DC-Input Module  
Telecommunication

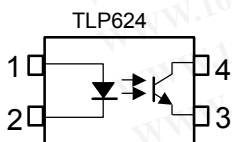
The TOSHIBA TLP624, -2 and -4 consist of a gallium arsenide infrared emitting diode optically coupled to a photo-transistor.  
The TLP624-2 offers two isolated channels in an eight lead plastic DIP, while the TLP624-4 provides four isolated channels in a sixteen lead plastic DIP.

- Collector-emitter voltage: 55V min.
- Current transfer ratio

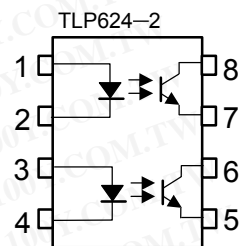
Classification	Current Transfer Ratio(min)			Marking of classification
	Ta = 25°C		Ta = -25~75°C	
Rank BV	If=1mA VCE=0.5V	If=0.5mA VCE=1.5V	If=1mA VCE=0.5V	BV
Standard	200%	100%	100%	BV,blank

- Isolation voltage: 5000V<sub>rms</sub> min.
- UL recognized: UL1577, file No.E67349
- BSI approved: BS EN60065: 1994 Certificate No.7426  
BS EN60950: 1992 Certificate No.7427
- Note: Application type name for certification test, please use standard product type name, i.e.  
TLP624(BV): TLP624  
TLP624-2(BV): TLP624-2

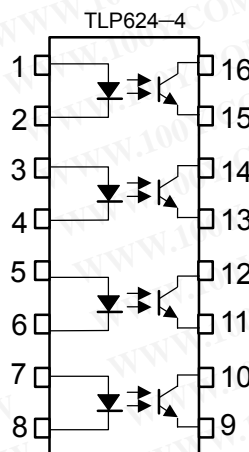
## Pin Configurations(top view)



- 1. Anode
- 2. Cathode
- 3. Emitter
- 4. Collector

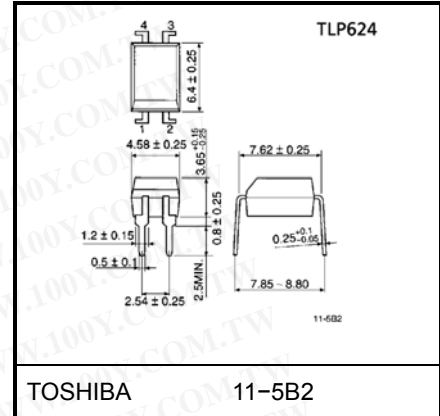


- 1,3 : Anode
- 2,4 : Cathode
- 5,7 : Emitter
- 6,8 : Collector



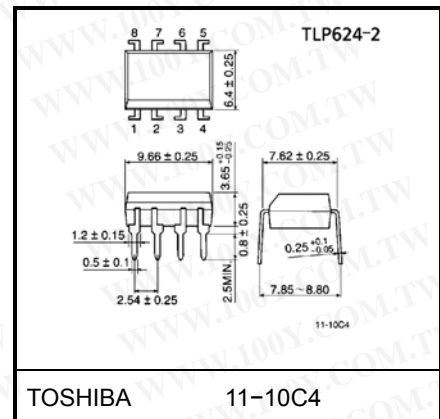
- 1,3,5,7: Anode
- 2,4,6,8: Cathode
- 9,11,13,15: Emitter
- 10,12,14,16: Collector

Unit in mm



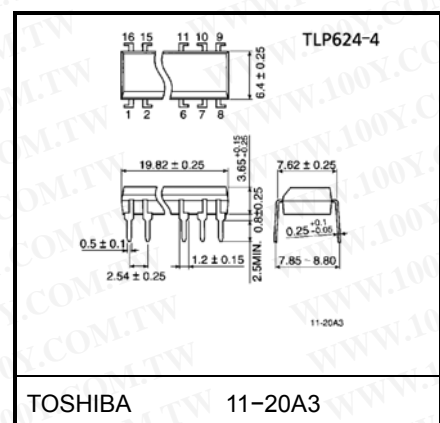
TOSHIBA 11-5B2

Weight: 0.26 g



TOSHIBA 11-10C4

Weight: 0.54 g



TOSHIBA 11-20A3

Weight: 1.1 g

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**勝特力电子(深圳) 86-755-83298787**  
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## Maximum Ratings (Ta = 25°C)

Characteristic		Symbol	Rating		Unit
			TLP624	TLP624-2 TLP624-4	
LED	Forward current	$I_F$	60	50	mA
	Forward current derating	$\Delta I_F / ^\circ\text{C}$	-0.7(Ta $\geq$ 39°C)	-0.5(Ta $\geq$ 25°C)	mA / °C
	Pulse forward current	$I_{FP}$	1(100 $\mu$ s, pulse, 100pps)		A
	Power dissipation(1 Circuit)	$P_D$	100	70	mW
	Power dissipation derating (Ta $\geq$ 25°C, 1 Circuit)	$\Delta P_D / ^\circ\text{C}$	-1.0	-0.7	mW / °C
	Reverse voltage	$V_R$	5		V
	Junction temperature	$T_j$	125		°C
Detector	Collector-emitter voltage	$V_{CEO}$	55		V
	Emitter-collector voltage	$V_{ECO}$	7		V
	Collector current	$I_C$	50		mA
	Collector power dissipation(1 circuit)	$P_C$	150	100	mW
	Collector power dissipation derating (Ta $\geq$ 25°C, 1 Circuit)	$\Delta P_C / ^\circ\text{C}$	-1.5	-1.0	mW / °C
	Junction temperature	$T_j$	125		°C
	Storage temperature range	$T_{stg}$	-55~125		°C
Operating temperature range	$P_{opr}$	-55~100		°C	
Lead soldering temperature	$T_{sol}$	260(10s)		°C	
Total package power dissipation(1 Circuit)	$P_T$	250	150	mW	
Total package power dissipation derating (Ta $\geq$ 25°C, 1 Circuit)	$\Delta P_T / ^\circ\text{C}$	-2.5	-1.5	mW / °C	
Isolation voltage	(Note 1) $BV_S$	5000(AC, 1min., RH $\leq$ 60%)		Vrms	

(Note 1) Device considered a two terminal device: LED side pins shorted together, and detector side pins shorted together.

## Recommended Operating Conditions

Characteristic	Symbol	Min.	Typ.	Max.	Unit
Supply voltage	$V_{CC}$	—	5	24	V
Forward current	$I_F$	—	1.6	20	mA
Collector current	$I_C$	—	1	10	mA
Operating temperature	$T_{opr}$	-25	—	75	°C

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## Individual Electrical Characteristics (Ta = 25°C)

Characteristic		Symbol	Test Condition	Min.	Typ.	Max.	Unit
LED	Forward voltage	$V_F$	$I_F = 10\text{mA}$	1.0	1.15	1.3	V
	Reverse current	$I_R$	$V_R = 5\text{V}$	—	—	10	$\mu\text{A}$
	Capacitance	$C_T$	$V = 0, f = 1\text{MHz}$	—	30	—	pF
Detector	Collector-emitter breakdown voltage	$V_{(BR)CEO}$	$I_C = 0.5\text{mA}$	55	—	—	V
	Emitter-collector breakdown voltage	$V_{(BR)ECO}$	$I_E = 0.1\text{mA}$	7	—	—	V
	Collector dark current	$I_{CEO}$	$V_{CE} = 24\text{V}$	—	10	100	nA
			$V_{CE} = 24\text{V}, T_a = 85^\circ\text{C}$	—	2	50	$\mu\text{A}$
Capacitance collector to emitter	$C_{CE}$	$V=0, f=1\text{MHz}$	—	12	—	pF	

## Coupled Electrical Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Current transfer ratio	$I_C / I_F$	$I_F = 1\text{mA}, V_{CE} = 0.5\text{V}$ Rank BV	100	—	1200	%
			200	—	1200	
Low input CTR	$I_C / I_F$ (low)	$I_F = 0.5\text{mA}, V_{CE} = 1.5\text{V}$ Rank BV	50	—	—	%
			100	—	—	
Collector-emitter saturation voltage	$V_{CE}$ (sat)	$I_C = 0.5\text{mA}, I_F = 1\text{mA}$ $I_C = 1\text{mA}, I_F = 1\text{mA}$ Rank BV	—	—	0.4	V
			—	0.2	—	
			—	—	0.4	

## Coupled Electrical Characteristics (Ta = -25°C~75°C)

Characteristic	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Current transfer ratio	$I_C / I_F$	$I_F = 1\text{mA}, V_{CE} = 0.5\text{V}$ Rank BV	50	—	—	%
			100	—	—	
Low input CTR	$I_C / I_F$ (low)	$I_F = 0.5\text{mA}, V_{CE} = 1.5\text{V}$ Rank BV	—	50	—	%
			—	100	—	

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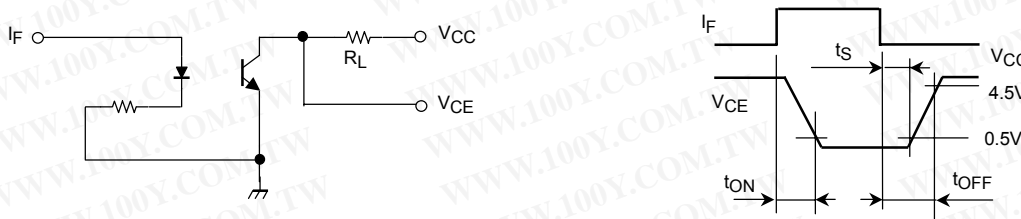
## Isolation Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Capacitance input to output	C <sub>S</sub>	V <sub>S</sub> = 0, f = 1MHz	—	0.8	—	pF
Isolation resistance	R <sub>S</sub>	V <sub>S</sub> = 500V	5×10 <sup>10</sup>	10 <sup>14</sup>	—	Ω
Isolation voltage	BV <sub>S</sub>	AC, 1minute	5000	—	—	V <sub>rms</sub>
		AC, 1second, in oil	—	10000	—	
		DC, 1 minute, in oil	—	10000	—	V <sub>dc</sub>

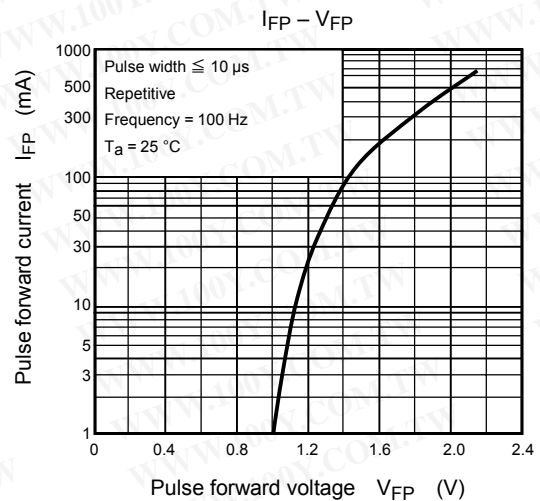
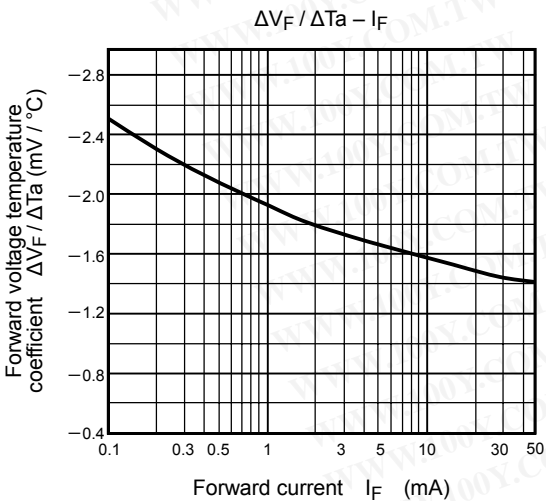
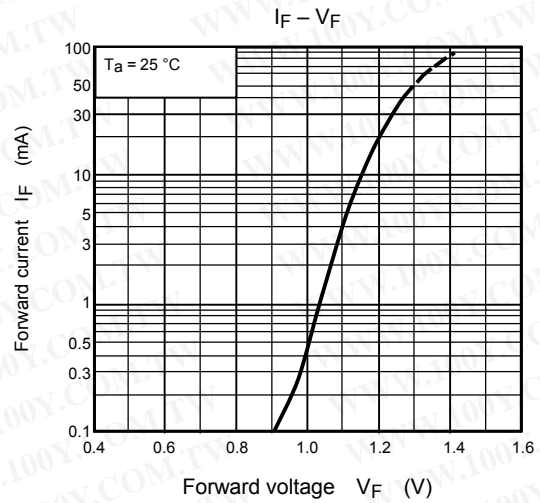
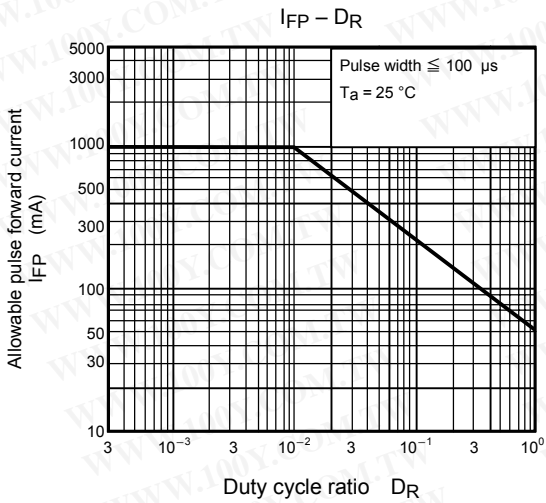
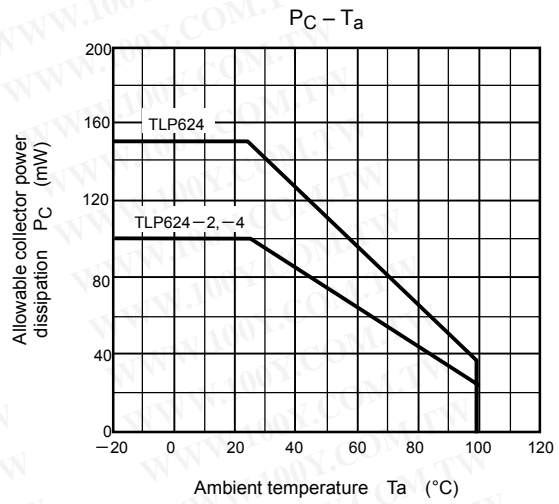
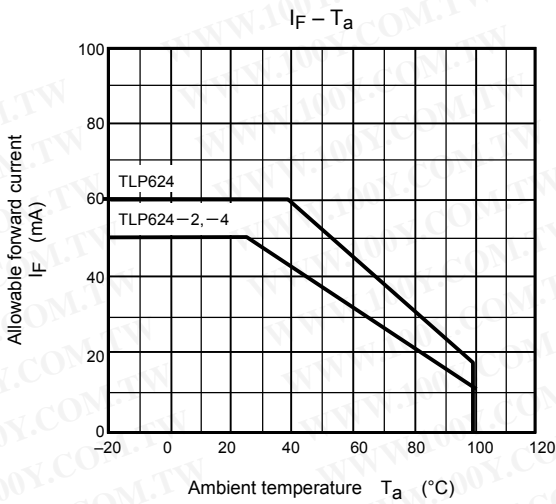
## Switching Characteristics (Ta = 25°C)

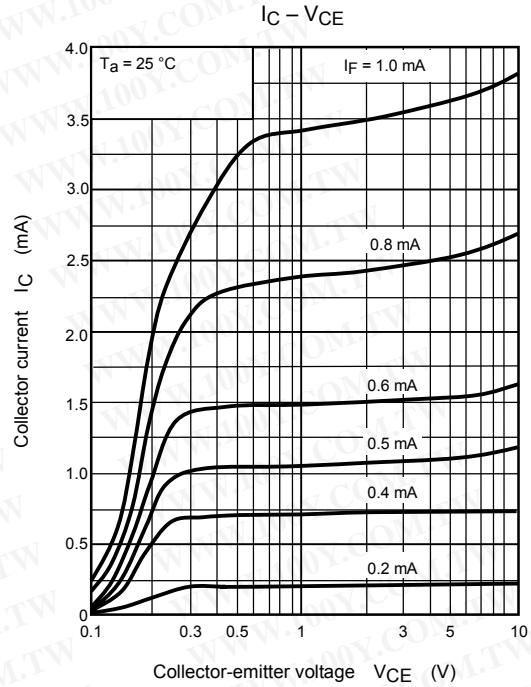
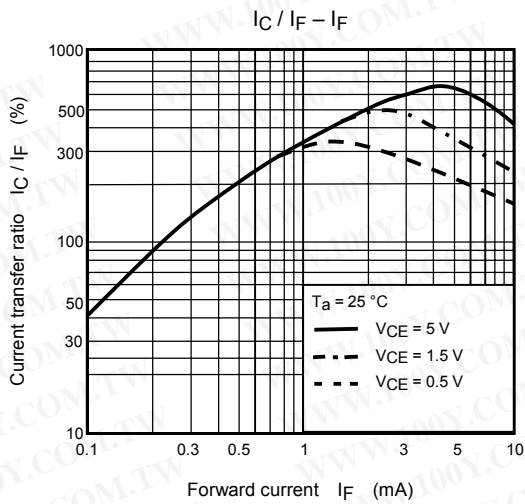
Characteristic	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Rise time	t <sub>r</sub>	V <sub>CC</sub> = 10V, I <sub>C</sub> = 2mA R <sub>L</sub> = 100Ω	—	8	—	μs
Fall time	t <sub>f</sub>		—	8	—	
Turn-on time	t <sub>on</sub>		—	10	—	
Turn-off time	t <sub>off</sub>		—	8	—	
Turn-on time	t <sub>ON</sub>	R <sub>L</sub> = 4.7 kΩ (Fig.1) V <sub>CC</sub> = 5 V, I <sub>F</sub> = 1.6mA	—	10	—	μs
Storage time	t <sub>S</sub>		—	50	—	
Turn-off time	T <sub>OFF</sub>		—	300	—	

Fig. 1 Switching time test circuit

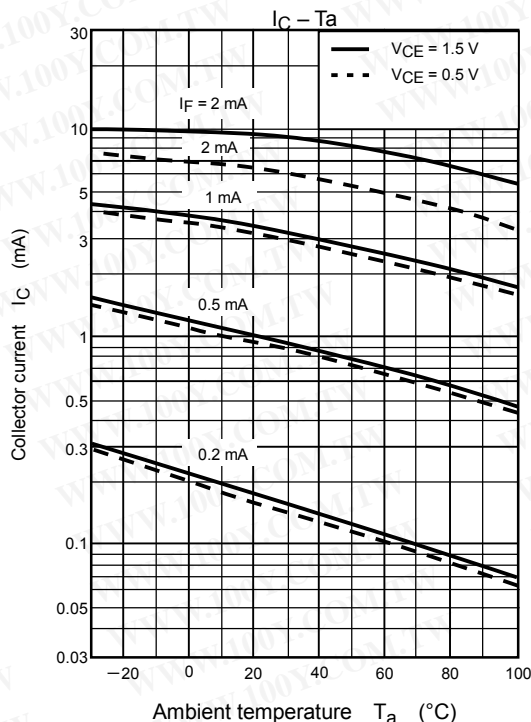
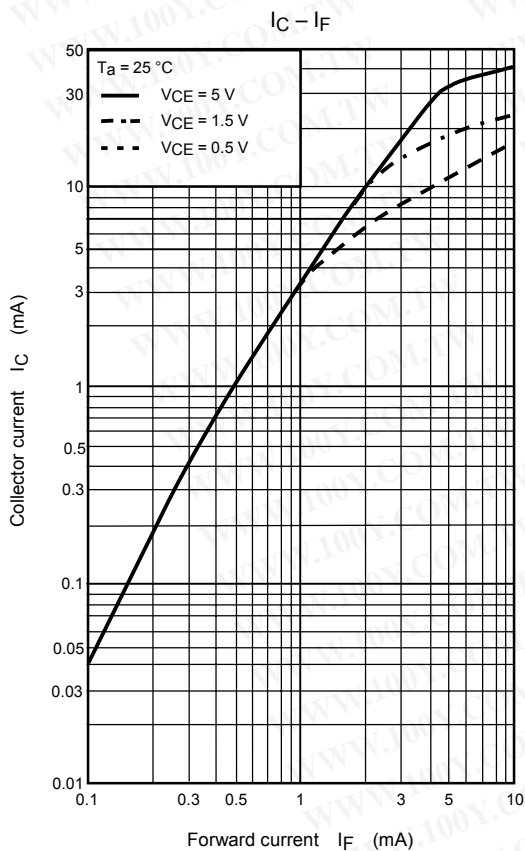


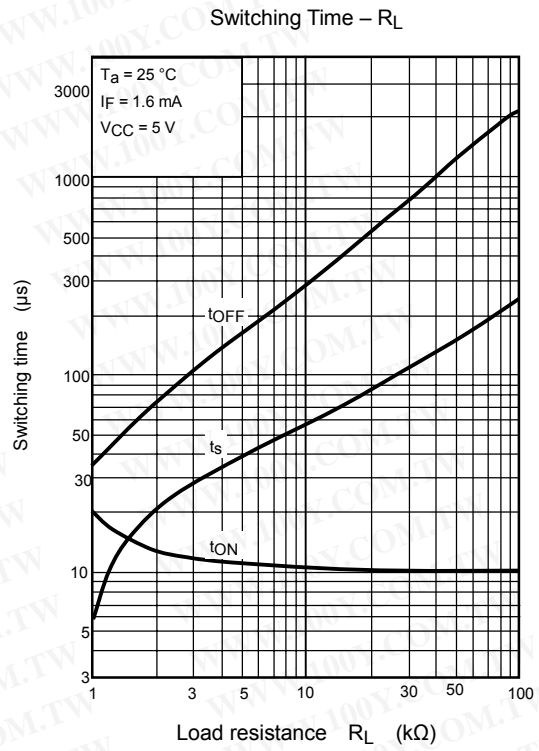
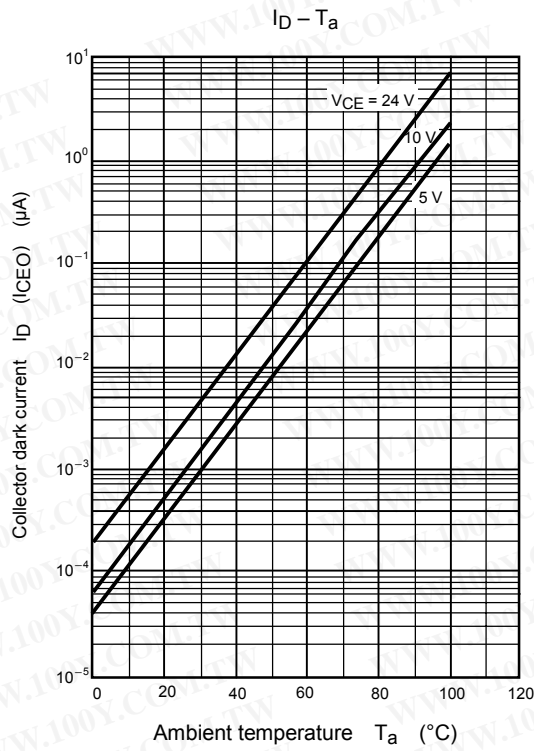
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